## NSN 5962-01-260-8676

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Body Length:         1.375 inches         Body Widh:         0.500 inches         Body Height:         0.185 inches         Maximum Power Dissipation Rating:         1.0 watts         Operating Tempurature Range:         -55.0/+125.0 degrees celsius         Storage Tempurature Range:         -65.0/+125.0 degrees celsius         Fortures Provided:         Monoithic and static operation         Inclosure Material:         Metal or plaster or ceramic         Inclosure Configuration:         Dual-Inline         Output Logic Form:         Complementary-metal exide-semiconductor logic         Input Circuit Pattern:         21 Input         Complementary-metal exide-semiconductor logic         Interminal Surface Treatment:         Solder         Voltage Rating And Type Per Characteristic:         7.0 volts power source         Memory Device Type:         Ram         Solder         Solder         Solder         Solder         Solder         Solder         Solder         Solder         Solder         Solder <th></th> <th></th>		
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Body Height:         0.185 inches         Maximum Power Dissipation Rating:         1.0 witls         Operating Tempurature Range:         -65.04-125.0 degrees celsius         Bottage Tempurature Range:         -65.04-150.0 degrees celsius         Features Provided:         Monotific and static operation         Inclosure Material:         Motal of plastic or ceramic         Inclosure Configuration:         Dual-in-line         Output Logic Forn:         Complementary-metal oxide-semiconductor logic         Input Crucut Pattern:         21 input         Case Outline Source And Designator:         2-10 mili-m-38510         Current Rating Per Characteristic:         80:00 militamperes reverse current, do absolute         Terminal Surface Treatment:         Solder         Yottas power source         Memory Device Type:         Ram         Terminal Type And Quantity:         4900-mili-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).         Furmical Type And Quantity:         Wa         Hatter         Na         Guide direcuit         Hatter <t< th=""><th>Body Width:</th><th></th></t<>	Body Width:	
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Yes - demil/mli	Demilitarization:	
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